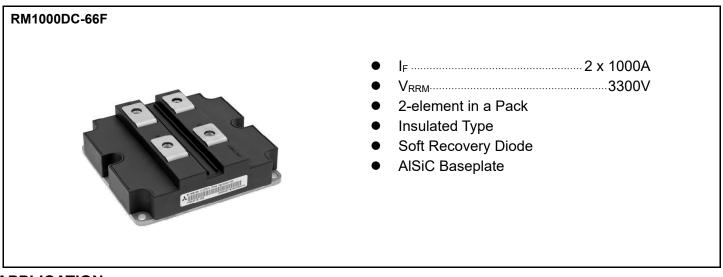


< HIGH VOLTAGE DIODE MODULES >

RM1000DC-66F

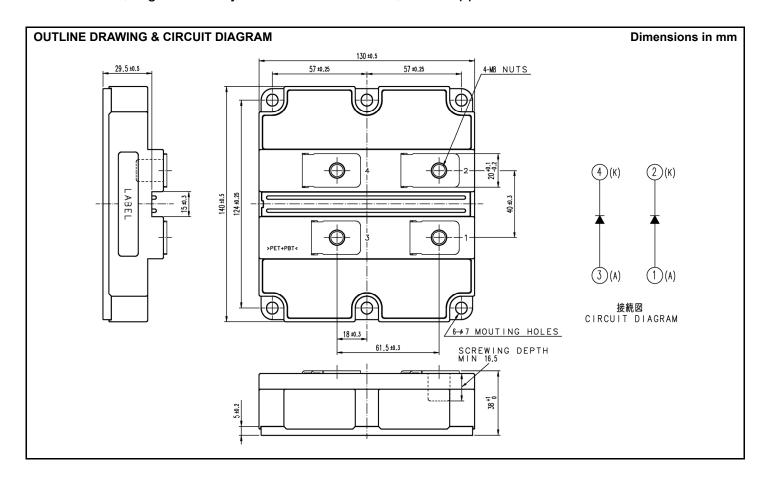
HIGH POWER SWITCHING USE INSULATED TYPE

High Voltage Diode Modules



APPLICATION

Traction drives, High Reliability Converters / Inverters, DC choppers



MAXIMUM RATINGS

Symbol	Item	Conditions	Ratings	Unit
V_{RRM}	Repetitive peak reverse voltage	$T_j = -40+125$ °C	3300	V
		$T_j = -50$ °C	3200	V
I _F	Forward current	DC, T _c = 80°C	1000	Α
I _{FSM}	Surge (non-repetitive) forward current	T_{j_start} = 125°C, t_p = 10 ms, Half-sine wave, V_R = 0	9.4	kA
l ² t	Surge current load integral	V	440	kA ² s
P _{tot}	Maximum power dissipation	T _c = 25°C	5200	W
V _{iso}	Isolation voltage	RMS, sinusoidal, f = 60 Hz, t = 1 min.	6000	V
V _e	Partial discharge extinction voltage	RMS, sinusoidal, f = 60 Hz, Q _{PD} ≤ 10 pC	2600	V
Tj	Junction temperature		−50 ~ +150	°C
T_jop	Operating junction temperature		−50 ~ +150	°C
T _{stg}	Storage temperature		− 55 ~ + 150	°C

ELECTRICAL CHARACTERISTICS

Comple at	Item	Conditions		Limits			Unit
Symbol				Min	Тур	Max	Unit
			T _j = 25°C	_	_	1.5	
I _{RRM}	Repetitive reverse current	$V_{RM} = V_{RRM}$	T _j = 125°C	_	1.5	_	mA
			T _i = 150°C	_	8.0		1
	Forward voltage	I _F = 1000 A	T _j = 25°C	1	2.20		٧
V_{FM}			T _j = 125°C	_	2.40	2.90	
			T _i = 150°C	_	2.35	_	
	Reverse recovery time		T _i = 25°C	_	0.65	0.65 —	
t _{rr}			T _i = 125°C	_	0.85	_	μs
		\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	T _i = 150°C	_	0.95	_	
	Reverse recovery current	$V_{CC} = 1800 \text{ V}$ $I_F = 1000 \text{ A}$	T _i = 25°C	_	800	_	А
I _{rr}		$-d_{iF}/d_{t} =$	T _i = 125°C	_	970	_	
			T _i = 150°C	_	1000	_	
	Reverse recovery charge	" -	T _i = 25°C	_	670	_	
Q_{rr}		3700 A/µs @ T _j = 25°C	T _i = 125°C	_	1100	_	μC
		3500 A/µs @ T _j = 125°C	T _i = 150°C	_	1300	_	
E _{rec(10%)}	Reverse recovery energy (Note 1)	3400 A/μs @ T _j = 150°C	T _i = 25°C	_	0.70	_	
			T _i = 125°C	_	1.20	_	J
		$L_s = 150 \text{ nH}$	T _i = 150°C	_	1.35	_	
	Reverse recovery energy	Inductive load	T _i = 25°C	_	0.80	_	
E _{rec}			T _i = 125°C	_	1.35	_	J
			T _i = 150°C	_	1.55	_	

RM1000DC-66F HIGH POWER SWITCHING USE INSULATED TYPE

THERMAL CHARACTERISTICS

Symbol	Item	Conditions	Limits			l locit
		Conditions	Min	Тур	Max	Unit
R _{th(j-c)}	Thermal resistance	Junction to Case (per 1/2 module)	-		24.0	K/kW
R _{th(c-s)}	Contact thermal resistance	Case to heat sink, λ_{grease} = 1 W/m k $D_{(c-s)}$ = 100 µm (per 1/2 module)		26.0	_	K/kW

MECHANICAL CHARACTERISTICS

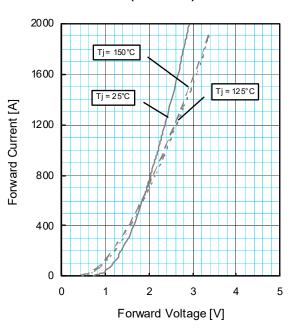
Symbol	Item	Conditions		Limits		
		Conditions	Min	Тур	Max	Unit
M_t	Mounting torque	M8 : Main terminals screw	7.0	_	22.0	N·m
Ms		M6 : Mounting screw	3.0	_	6.0	N·m
m	Mass		_	0.8	_	kg
CTI	Comparative tracking index		600	_	_	
d _a	Clearance		19.5	_	_	mm
d _s	Creepage distance		32.0	_	_	mm
L _{PAK}	Parasitic stray inductance	1/2 module	_	33.0	_	nΗ
R _{AA'+KK'}	Internal lead resistance	$T_c = 25$ °C, 1/2 module	_	0.14	_	mΩ

Note 1. $E_{rec(10\%)}$ is the integral of 0.1 V_R x 0.1 I_F x dt.

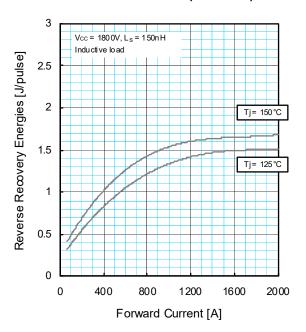
PERFORMANCE CURVES

INSULATED TYPE

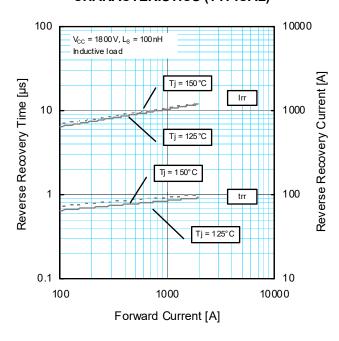
FORWARD CHARACTERISTICS (TYPICAL)



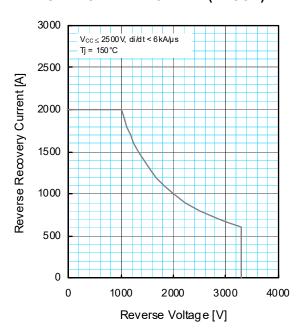
REVERSE RECOVERY ENERGY CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY CHARACTERISTICS (TYPICAL)



REVERSE RECOVERY SAFE OPERATING AREA (RRSOA)

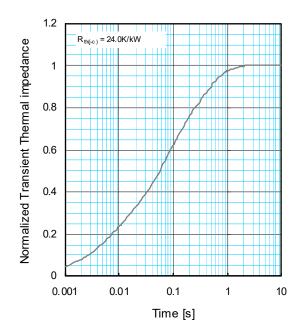


RM1000DC-66F

HIGH POWER SWITCHING USE INSULATED TYPE

PERFORMANCE CURVES

TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS



$$Z_{th(j-c)}(t) = \sum_{i=1}^{n} R_{i} \left\{ I - exp^{\left(-\frac{t}{\tau_{i}}\right)} \right\}$$

$$\frac{1}{R_{i} [\text{K/kW}]: \quad 0.0096 \quad 0.1893 \quad 0.4044 \quad 0.3967}$$

$$\tau_{i} [\text{sec}]: \quad 0.0001 \quad 0.0058 \quad 0.0602 \quad 0.3512}$$

INSULATED TYPE

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INSULATED TYPE

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